No. 20B-2 SbSI–SbOI

1b	$SbO_{0.2}S_{0.8}I$ shows a ferroelectric transition: Θ_f = 65 °C.	64Nit
	Θ_f as a function of sample location in polycrystalline ingots were given for $SbO_{0.05}S_{0.95}I$ and $SbO_{0.2}S_{0.8}I$.	64Nit
2a	Partial replacement of S by O in SbSI is possible under conservation of the SbSI structure, although the isostructual compound SbOI is not known to exist.	64Nit